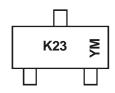


Marking Information



 $\begin{array}{l} \text{K23 = Product Type Marking Code} \\ \text{YM = Date Code Marking} \\ \text{Y or } \overline{\text{Y}} = \text{Year (ex: A = 2013)} \\ \text{M = Month (ex: 9 = September)} \end{array}$

Date Code Key

Year	2002	2003	2004	2005	2006		2012	2013	2014	2015	2016	2017	2018	2019
Code	N	Р	R	S	Т		Z	Α	В	С	D	E	F	G
Month	Jan	Feb	Ma	ar .	Apr	May	Jun	Jul	Aug	Se	р (Oct	Nov	Dec
Code	1	2	3	}	4	5	6	7	8	9		0	N	D

Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characte	ristic	Symbol	Value	Units
Drain-Source Voltage		V _{DSS}	100	V
Drain-Gate Voltage $R_{GS} \le 20K\Omega$		V_{DGR}	100	V
Gate-Source Voltage	Continuous	V _{GSS}	±20	V
Drain Current (Note 5)	Continuous Pulsed	I _D I _{DM}	170 680	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	P _D	200	mW
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage	BV_{DSS}	100	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current		_	_	1.0 10	μA nA	$V_{DS} = 100V, V_{GS} = 0V$ $V_{DS} = 20V, V_{GS} = 0V$	
Gate-Body Leakage, Forward	I _{GSSF}	_	_	50	nA	$V_{GS} = 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	$V_{GS(th)}$	0.8	1.4	2.0	V	$V_{DS} = V_{GS}$, $I_D = 1mA$	
Static Drain-Source On-Resistance	R _{DS(ON)}		_	6.0 10	Ω	$V_{GS} = 10V, I_D = 0.17A$ $V_{GS} = 4.5V, I_D = 0.17A$	
Forward Transconductance	g _F s	80	370	_	mS	$V_{DS} = 10V$, $I_D = 0.17A$, $f = 1.0KHz$	
Drain-Source Diode Forward Voltage		_	0.84	1.3	V	$V_{GS} = 0V, I_{S} = 0.34A$	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	Ciss	_	29	60	pF		
Output Capacitance		_	10	15	pF	$V_{DS} = 25V, V_{GS} = 0V, f = 1.0MHz$	
Reverse Transfer Capacitance		_	2	6	pF]	
SWITCHING CHARACTERISTICS(Note 7)							
Turn-On Rise Time	t _r	_	_	8	ns		
Turn-Off Fall Time Turn-On Delay Time		_	_	16	ns	$V_{DD} = 30V, I_D = 0.28A,$	
		_	_	8	ns	$R_{GEN} = 6.0\Omega$, $V_{GS} = 10V$	
Turn-Off Delay Time	t _{D(OFF)}	_		13	ns		

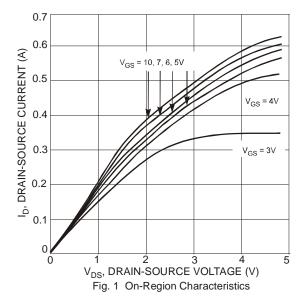
Notes: 5. Part mounted on FR-4 board with recommended pad layout, which can be found on our website at http://www.diodes.com.

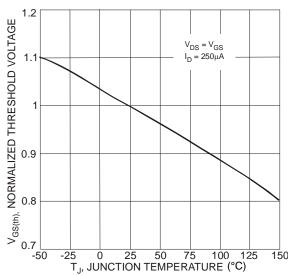
Downloaded from **Arrow.com**.

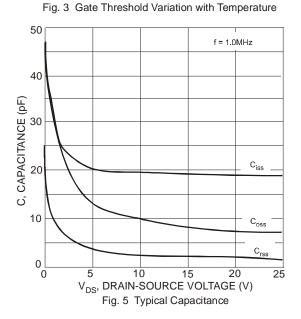
^{6.} Short duration pulse test used to minimize self-heating effect.

^{7.} Guaranteed by design. Not subject to production testing.









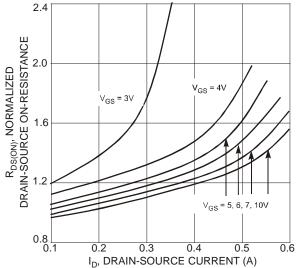


Fig. 2 On-Resistance Variation with Gate Voltage and Drain-Source Current

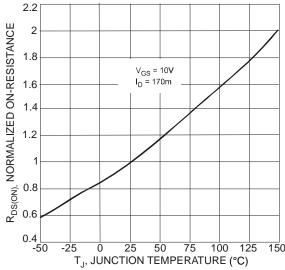


Fig. 4 On-Resistance Variation with Temperature

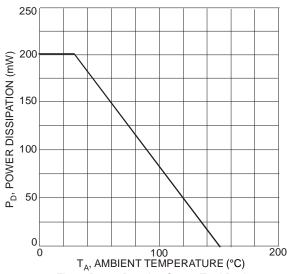
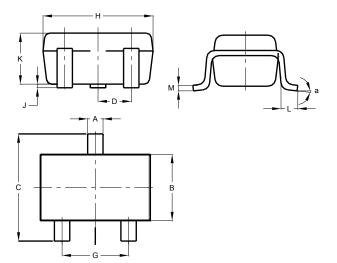


Fig. 6 Power Derating Curve, Total Package



Package Outline Dimensions

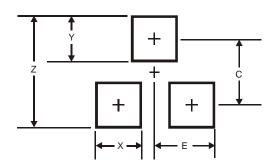
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT323							
Dim	Min	Max	Тур				
Α	0.25	0.40	0.30				
В	1.15	1.35	1.30				
С	2.00	2.20	2.10				
D	0.650 BSC						
F	0.375	0.475	0.425				
G	1.20	1.40	1.30				
Н	1.80	2.20	2.15				
J	0.00	0.10	0.05				
K	0.90	1.00	0.95				
L	0.25	0.40	0.30				
M	0.10	0.18	0.11				
а	8°C						
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)			
Z	2.8			
Х	0.7			
Y	0.9			
С	1.9			
E	1.0			



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